ACOUSTAR))

HIGH FIDELITY CLASS D AUDIO AMPLIFIER SOLUTION

DESCRIPTION

The ZXCD1010 provides complete control and modulation functions at the heart of a high efficiency high performance Class D switching audio amplifier solution. In combination with matched output magnetics and Zetex HDMOS MOSFET devices, the ZXCD1010 provides a high performance Class D audio amplifier with all the inherent benefits of Class D.

The ZXCD1010 is an enhanced version of the ZXCD1000. The timing resistor for the oscillator is taken off the chip enabling improved oscillator frequency matching device to device.

The ZXCD1010 solution uses proprietary circuitry and magnetic technology to realise the true benefits of Class D without the traditional drawback of poor distortion performance. The combination of circuit design, magnetic component choice and layout are essential to realising these benefits.

The ZXCD1010 reference designs give output powers up to 100W rms with typical open loop (no feedback) distortions of less than 0.2% THD + N over the entire audio frequency range at 90% full output power. This gives an extremely linear system. The addition of a minimum amount of feedback (10dB) further reduces distortion figures to give < 0.1 % THD + N typical at 1kHz.

From an acoustic point of view, even more important than the figures above, the residual distortion is almost totally free of any crossover artifacts. This allows the ZXCD1010 to be used in true hi-fi applications. This lack of crossover distortion, sets the ZXCD1010 solutions quite apart from most other presently available solutions.

FEATURES

- 90% efficiency

- External R_{OSC} C_{OSC} for improved accuracy

- 4 / 8 Ω drive capability

- Noise Floor -115dB for solution

- Flat response 20Hz - 20kHz

- High gate drive capability (2200pF)

- Very low THD + N 0.2% typical of full power up to 90% (for the solution)

- Complete absence of crossover artifacts

- OSC output available for sync in multi-channel applications

- Available in a 16 pin exposed pad QSOP package

- Refer to ZXCD1000 data sheet for typical characteristics and applications indormation

APPLICATIONS

- DVD receivers

- Automotive audio systems

- Home Theatre

- Multimedia

- Wireless speakers

- Portable audio

- Sub woofer systems

- Public Address systems

Distortion v Power (8Ω open loop at 1kHz.)

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ZXCD1010

ABSOLUTE MAXIMUM RATINGS

Terminal Voltage with respect to G_{ND}

V_{CC}	20V
Power Dissipation	1W
Package Thermal Resistance (Θ_{ja})	54°C/W
Operating Temperature Range	-40°C to 70°C
Maximum Junction Temperature	125°C
Storage Temperature Range	-50°C to 85°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS (unless otherwise stated) V_{CC} = 16V, T_A = 25°C

SYMBOL	PARAMETER	CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
V_{CC}	Operating Voltage Range		12	16	18	V
I_{ss}	Operating Quiescent Current	V_{CC} = 12V V_{CC} = 18V, 16V			45 50	mA mA
F_{osc}	Switching Frequency	C_{OSC} = 330pF, R_{OSC} = 31k5	173	192	211	kHz
$F_{osc(tol)}$	Frequency Tolerance	C_{OSC} = 330pF, R_{OSC} = 31k5			+/-10	%
Vol OutA/B	Low level output voltage	No load			100	mV
Voh OutA/B	High level output voltage	No load	7.5			V
T_{Drive}	Output Drive Capability (OUT A / B Rise/Fall)	Load Capacitance = 2200pF		50		ns
5V5tol	Internal Rail Tolerance	1µF Decoupling	5.16	5.5	5.77	V
9VA/Btol	Internal Rail Tolerance	1µF Decoupling	8.32	8.75	9.18	V
Audio A / B	Input Impedence		1.35k	1.8k	2.3k	Ω
Triangle A / B	Input Impedence		1.35k	1.8k	2.3k	Ω
Audio A / B	Bias Level		2.95	3.1	3.25	V
Triangle A / B	Bias Level		2.95	3.1	3.25	V
Osc A / B	Amplitude		0.89	1.05	1.2	V

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Pin number	Pin Name	Pin Description
1	Audio A	Audio Input for Channel A
2	Triangle A	Triangle Input for Channel A
3	Osc A	Triangle Output
4	R_{osc}	External timing resistor node (to set the switching frequency)
5	C_{osc}	External timing capacitor node (to set the switching frequency)
6	Osc B	Triangle Output (for slave ZXCD1010 in stereo application)
7	Triangle B	Triangle Input for Channel B
8	Audio B	Audio Input for Channel B
9	Gnd	Small Signal GND
10	OUT B	Channel B PWM Output to drive external Bridge MOSFETs
11	Gnd2	Power GND (for Output Drivers)
12	9VB	Internal Supply Rail (Decouple with 1µF Cap)
13	VCC	Input Supply Pin (Max = 18V)
14	9VA	Internal Supply Rail (Decouple with 1µF Cap).
15	OUT A	Channel A PWM Output to drive external Bridge MOSFETs
16	5V5	Internal Supply Rail (Decouple with 1µF Cap)
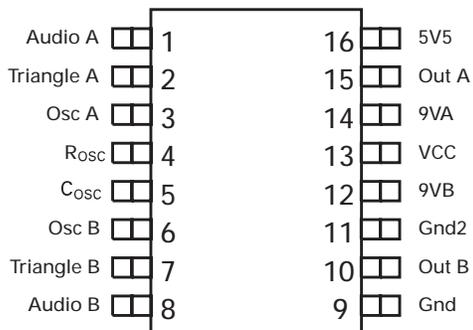
Figure 1
Pin Connection Diagram

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ZXCD1010

ZXCD1010 Class D controller IC

A functional block diagram of the ZXCD1010 is shown in Figure 2. The on chip series regulators drop the external V_{CC} supply (12V-18V) to the approximate 9V (9VA/9VB) and 5.5V (5V5) supplies required by the internal circuitry.

A triangular waveform is generated on chip and is brought out at the OscA and OscB outputs. The frequency of this is set (to ~200kHz) by an external capacitor (C_{osc}) and resistor (R_{osc}). The triangular waveform must be externally AC coupled back into the ZXCD1010 at the TriangleA and TriangleB inputs.

AC coupling ensures symmetrical operation resulting in minimal system DC offsets. TriangleA is connected to one of the inputs of a comparator and TriangleB is connected to one of the inputs of a second comparator. The other inputs of these two comparators are connected to the AudioA and AudioB inputs, which are anti-phase signals externally derived from the audio input. The triangular wave is an order higher in frequency than the audio input (max 20kHz). The outputs of the comparators toggle every time the TriangleA/B and the (relatively slow) AudioA/B signals cross.
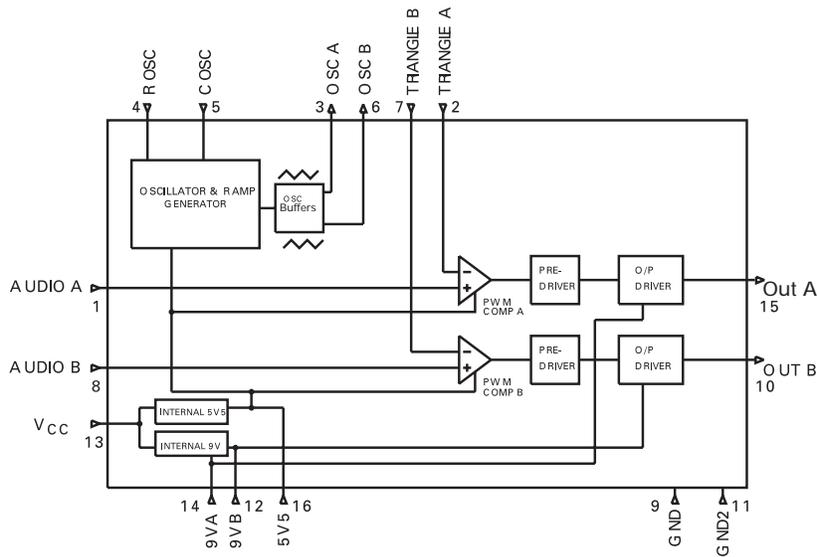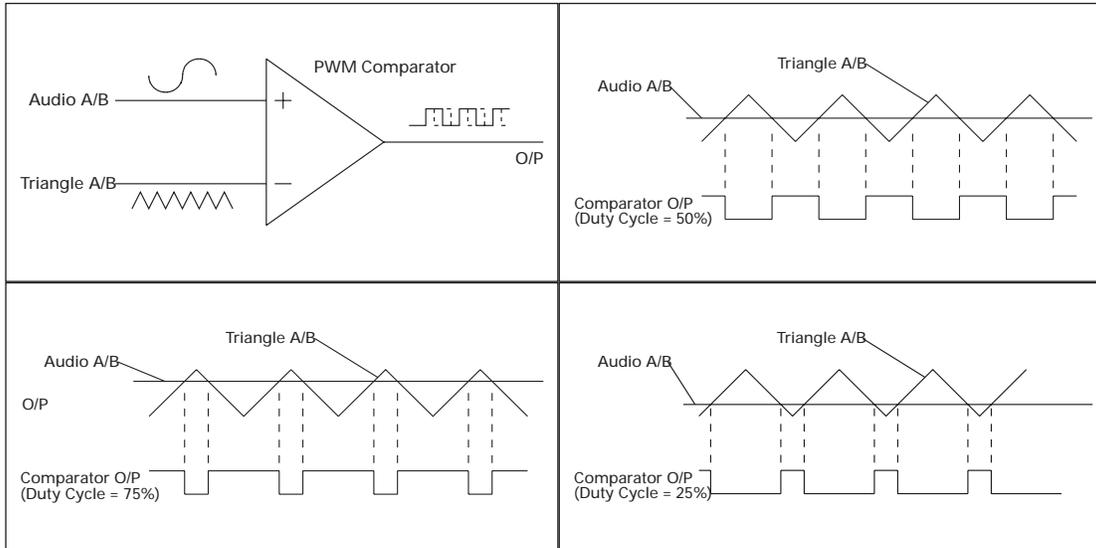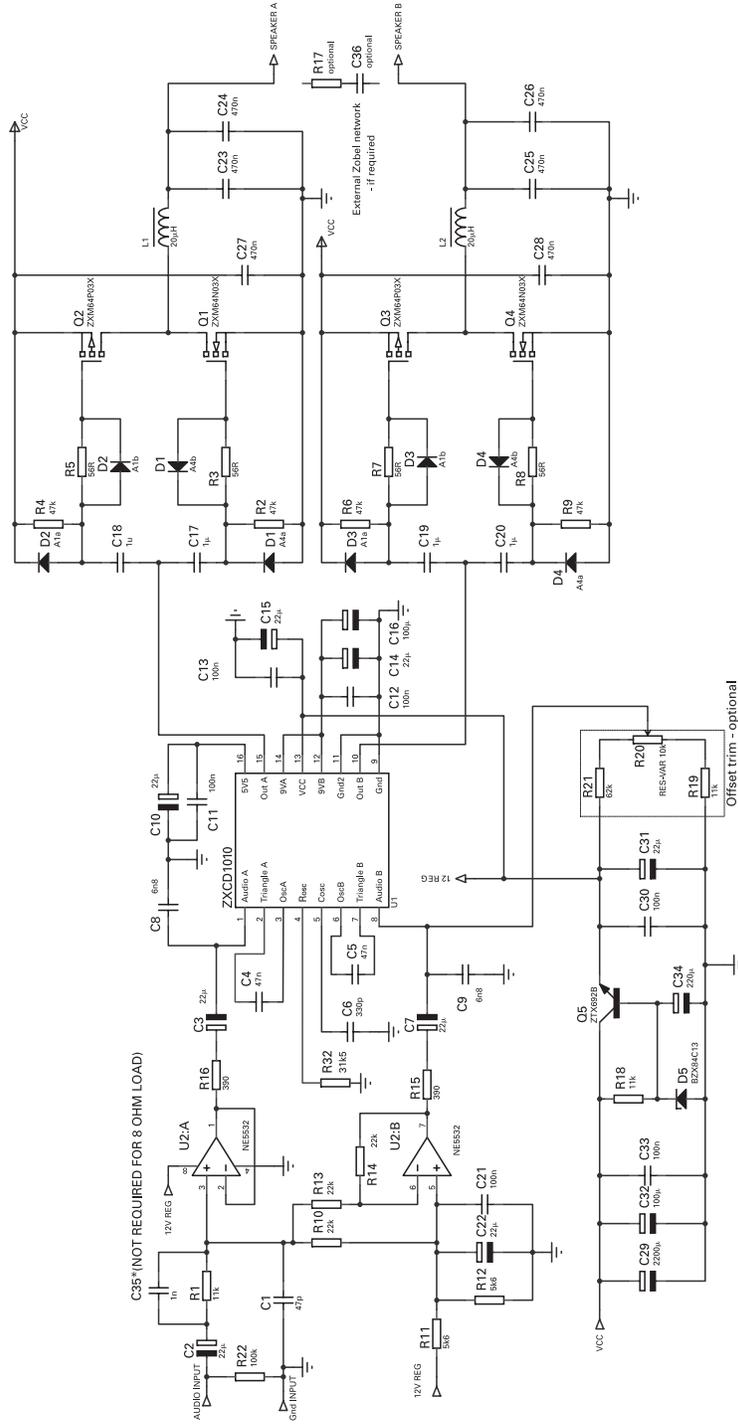

Figure 2
Functional Block Diagram

Figures 3a,3b,3c and 3d
The audio input Pulse Width Modulates the comparator output

With no audio input signal applied, the AudioA/B inputs are biased at the mid-point of the triangular wave, and the duty cycle at the output of the comparators is nominally 50%. As the AudioA/B signal ascends towards the peak level, the crossing points with the (higher frequency) triangular wave also ascend. The comparator monitoring these signals exhibits a corresponding increase in output duty cycle. Similarly, as the AudioA/B signal descends, the duty cycle is correspondingly reduced. Thus the audio input Pulse Width Modulates the comparator outputs. This principle is illustrated in Figures 3a, b, c and d. The comparator outputs are buffered and used to drive the OutA and OutB outputs. These in turn drive the speaker load (with the audio information contained in the PWM signal) via the off chip output bridge and single stage L-C filter network.

The ramp amplitude is approximately 1V. The AudioA, AudioB, TriangleA and TriangleB inputs are internally biased to a DC voltage of approximately VCC/5. The mid - point DC level of the OscA and OscB triangular outputs is around 2V. The triangular wave at the Cosc pin traverses between about 2.7V and 3.8V and the dist pin exhibits a roughly square wave from about 1.4V to 2V. (The above voltages may vary in practice and are included for guidance only).

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Figure 4
Zetex Class D 25W Mono Open Loop Solution

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Class D 25W Mono Open Loop (Bridge Tied Load - BTL) Solution – Circuit Description

Proprietary circuit design and high quality magnetics are necessary to yield the high THD performance specified. Deviation from the Zetex recommended solution could significantly degrade performance.

The speaker is connected as a Bridge Tied Load (BTL). This means that both sides of the speaker are driven from the output bridge and therefore neither side of the speaker connects to ground. This allows maximum power to be delivered to the load, from a given supply voltage. The supply voltage for this solution is nominally 16V for 25W into a 4Ω load.

A schematic diagram for the solution is shown in Figure 4. The audio input is AC coupled and applied to a low pass filter and a phase splitter built around the NE5532 dual op-amp. One of these op-amps is configured as a voltage follower and the other as a X1 inverting amplifier. This produces in phase and inverted signals for application to the ZXCD1010. The op-amp outputs are AC coupled into the ZXCD1010 Audio A and Audio B inputs via simple R-C low pass filters (R16/C3 and R15/C7). The op-amps are biased to a DC level of approximately 6V by R11 and R12.

The Pulse Width Modulated (PWM) outputs, OutA and OutB, which contain the audio information, are AC coupled and DC restored before driving the Zetex ZXM64P03X and ZXM64N03X PMOS and NMOS output bridge FET's. AC coupling is via C17, C18, C19 and C20. DC restoration is provided by the D2(A1a)/R4, D1(A4a)/R2 and D3(A1a)/R6, D4(A4a)/R9 components. This technique allows the output stage supply voltage to be higher than the high level of the OutA and OutB outputs (approximately 8.5V), whilst still supplying almost the full output voltage swing to the gates of the bridge FET's (thereby ensuring good turn on). This can be exploited to yield higher power solutions with higher supply voltages – this is discussed later.

The resistor/diode combinations (R5/D2(A16b), R3/D1(A4b), R7/D3(A1b) and R8/D4(A4b)) in series with the bridge FET gates, assist in controlling the switching of the bridge FET's. This design minimises shoot through currents whilst still achieving the low distortion characteristics of the system.

The purpose of the special inductors in conjunction with the output capacitors C23, C24, C25 and C26 is to low pass filter the high frequency switching PWM signal that comes from the bridge. Thus the lower frequency audio signal is recovered and is available at the speakerA and speakerB outputs across which the speaker should be connected. Zetex can offer advice on suitable source for the specialist magnetics.

The optional components R17 and C3 form a Zobel network. The applicability of these depends upon the application and speaker characteristics. Suggested values are 47nF and 10 ohms

Efficiency

Figure 5 shows the measured efficiency of the Zetex solution at various power levels into both 4Ω and 8Ω loads. As a comparison, typical efficiency is plotted for a class A-B amplifier. They clearly demonstrate the major efficiency benefits available from the Zetex class D solution.
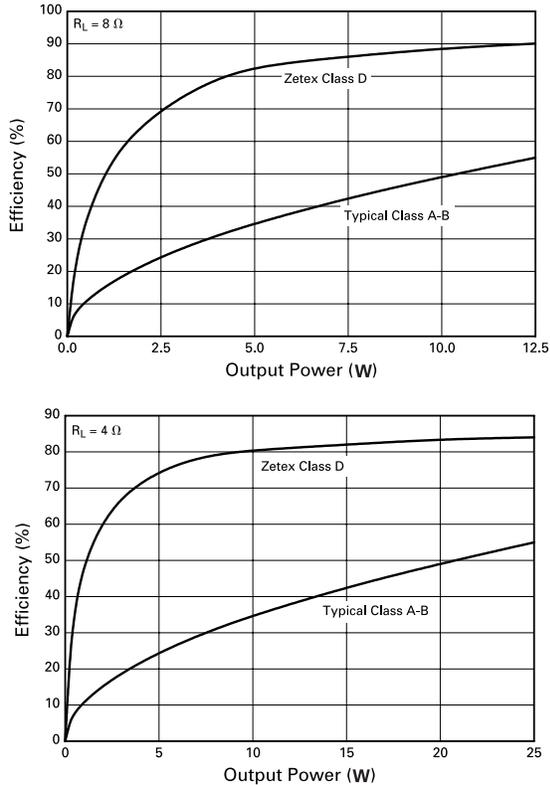

Figure 5
Output Stage Efficiency v Power with 4Ω and 8Ω loads

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ZXCD1010

Other Solutions - Stereo and Higher Powers

STEREO

It is possible to duplicate the above solution to give a 2 channel stereo solution. However if the oscillator frequencies are not locked together, a beat can occur which is acoustically audible. This is undesirable. A stereo solution which avoids this problem can be achieved by synchronising the operating frequencies of both ZXCD1010's class D controller IC's, by slaving one device from the other. This is illustrated in Figure 6.

Great care must be taken when linking the triangle from the master to the slave. Any pickup can cause slicing errors and result in increased distortion. The best connection method is to run two tracks, side by side, from the master to the slave. One of these tracks would be the triangle itself, and the other would be the direct local ground linking the master pin9 ground to the slave pin 9 ground.
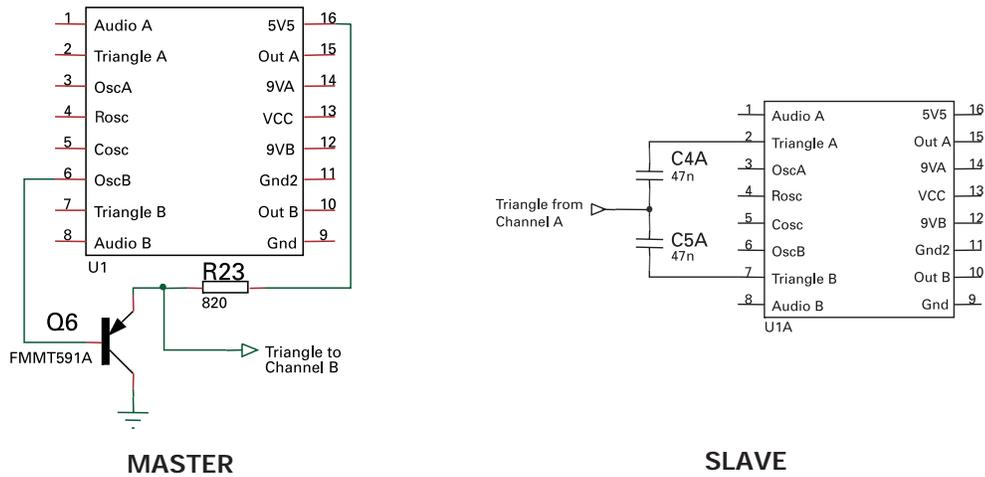
Figure 6
Frequency synchronisation for stereo applications

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Higher Power Solutions

With some modifications the applications solutions can be extended to give output power up to 100W. The main differences being the supply voltage, the TO220 MOSFETs (ZXM64N035L3 and ZXM64P035L3), and the output magnetics. The magnetics for 100W are necessarily larger than required for 25W in order to handle the higher load currents. For 100W operation the supply voltage to the circuit is nominally 35V with a 4Ω load.

The ZXCD1010 class D controller IC is inherently capable of driving even higher power solutions, with the appropriate external circuitry. However the maximum supply voltage to the ZXCD1010 class D controller IC is 18V so the higher supply voltages must therefore be dropped. Also due consideration must be given to the ZXCD1010 output drive levels and the characteristics of the bridge MOSFET's. The latter must be sufficiently enhanced by the OutA and OutB outputs to ensure the filter and load network is driven properly. If the gate drive of the ZXCD1010 is too low for the chosen MOSFET then the OUTA and OUTB signal must be buffered using an appropriate MOSFET driver circuit. Additionally, suitable magnetics are essential to achieve good THD performance.

Package details

The ZXCD1010 is available in a 16 pin exposed pad QSOP package. The exposed pad on the underside of the package should be soldered down to an area of copper on the PCB, to function as a heatsink. The PCB should have plated through vias to the underside of the board, again connecting to an area of copper.
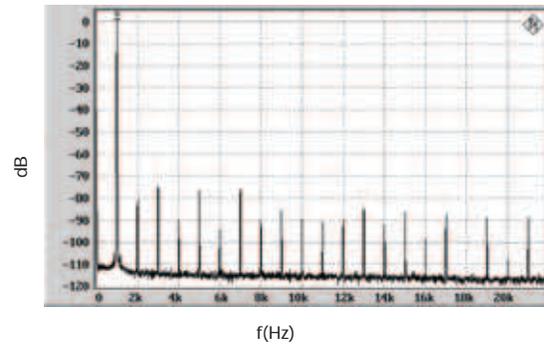
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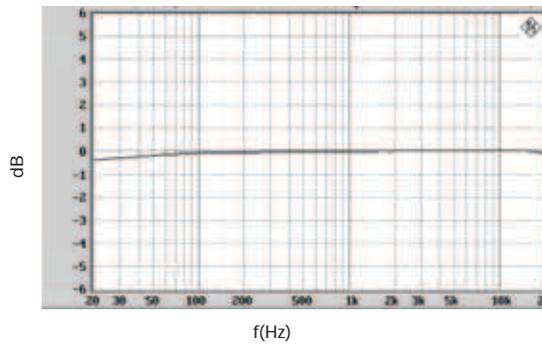## ZXCD1010 Solution performance figures

Typical performance graphs for the Zetex 25W open loop solution are shown here for both 4 and 8Ω loads. These graphs further demonstrate the true high fidelity performance achieved by the Zetex solutions.
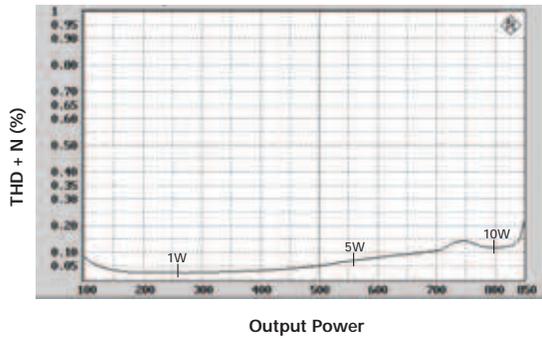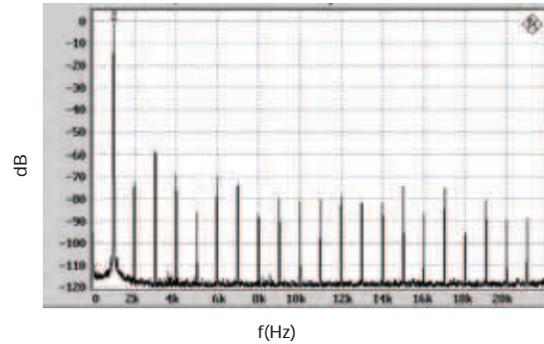

THD v Power into 8Ω at 1kHz
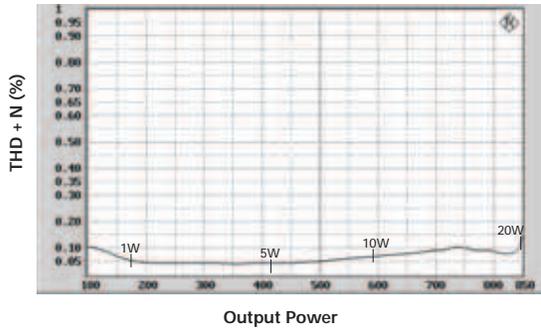

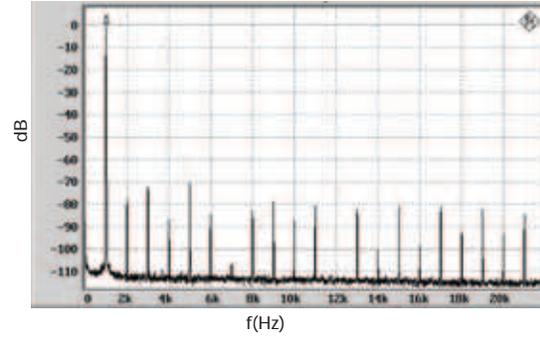FFT of distortion and noise floor at 1W (8Ω load)

Frequency response (8Ω load)
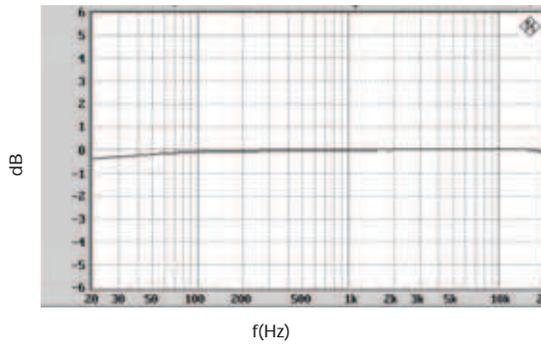

FFT of distortion and noise floor at 10W (8Ω load)

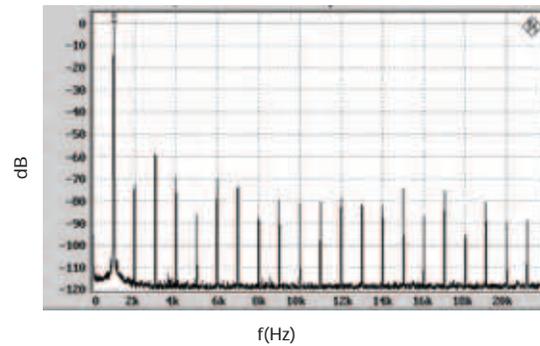**THD v Power into 4Ω at 1kHz**

FFT of distortion and noise floor at 1W (4Ω load)
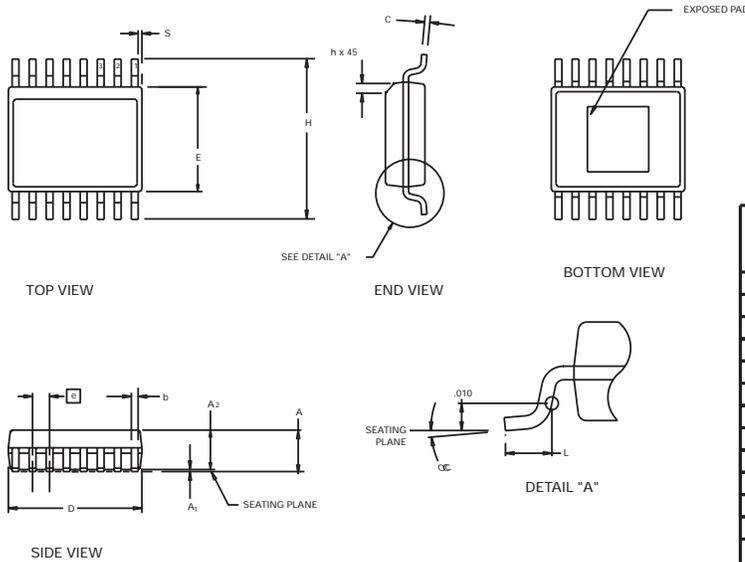

Frequency response (4Ω load)

Note roll off.
This can be corrected by using an alternative values for output filter components.

FFT of distortion and noise floor at 20W (4Ω load)

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PACKAGE DIMENSIONS

TOP VIEW

END VIEW

BOTTOM VIEW

EXPOSED PAD

SEE DETAIL "A"

SIDE VIEW

SEATING PLANE

DETAIL "A"

SYMBOL	DIMENSIONS IN INCHES		
	MIN.	NOM.	MAX.
A	.058	.061	.066
A₁	.001	.003	.005
A₂	.055	.058	.061
b	.008		.012
c	.007		.010
D	.189	.194	.196
E	.150	.154	.157
e	.025 BSC		
H	.228	.236	.244
h	.010	.013	.016
L	.016	.025	.035
S	.002	.005	.007
∝	0	5	8

ORDERING INFORMATION

Device	Description	Package	T&R Suffix
ZXCD1010EQ16	Class D modulator	QSOP16*	TA, TC

Information on Zetex reference designs, MOSFETs and demonstration boards can be obtain by contacting Zetex applications or by visiting www.zetex.com/audio

*This package features an exposed pad which must be soldered down.

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